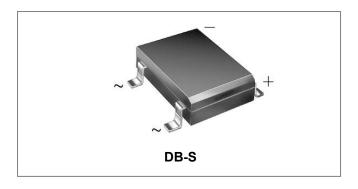




Technical Data Data Sheet N1459, Rev. B RoHS 🗭

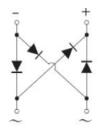
## DB101S THRU DB107S SINGLE-PHASE GLASS PASSIVATED SILICON BRIDGE RECTIFIERS



# Features

- Glass passivated die construction
- Low forward voltage drop
- High current capability
- High surge current capability
- Designed for surface mount application
- Plastic material-UL flammability 94V-0
  This is a Physical Device
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Circuit Diagram**



#### **Mechanical Data**

- Case: DB-S, molded plastic
- Terminals: plated leads solderable per MIL-STD-202, Method 208
- Polarity: as marked on case
- Mounting position: Any
- Lead Free: For RoHS / Lead Free Version,

#### Maximum Ratings@T<sub>A</sub>=25°C unless otherwise specified

Single Phase half wave 60Hz, resistive or inductive load. For capacitive load current derate by 20%.

Characteristic	Symbol	DB 101S	DB 102S	DB 103S	DB 104S	DB 105S	DB 106S	DB 107S	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	100	200	400	600	800	1000	v
RMS Reverse Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Average Forward Output Current (Note 1) @ $T_c$ =100°C	I <sub>F(AV)</sub>	1.0				А			
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	Ігѕм	45				A			
I <sup>2</sup> t Rating for Fusing (t < 8.3ms)	l²t	8.404				A <sup>2</sup> s			

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# DB101S THRU DB107S

#### **Technical Data** Data Sheet N1459, Rev. B

RoHS

## **Electrical Characteristics:**

Characteristic	Symbol	DB 101S	DB 102S	DB 103S	DB 104S	DB 105S	DB 106S	DB 107S	Unit
Maximum Forward Voltage Drop per Bridge Element $@I_F = 1.0A, T_J = 25^{\circ}C$	VF				1.0				V
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 125^{\circ}C$	I <sub>R</sub>				5 200				μA
Typical Junction Capacitance (Note 2)	CJ				25				pF

\* Pulse width < 300  $\mu$ s, duty cycle < 2%

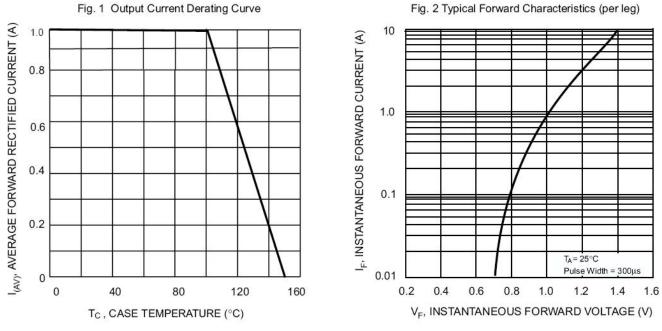
## **Thermal-Mechanical Specifications:**

Characteristic	Symbol	DB 101S	DB 102S	DB 103S	DB 104S	DB 105S	DB 106S	DB 107S	Unit
Typical Thermal Resistance Junction to Ambient	$R_{\theta JA}$	A 40			°C/W				
Typical Thermal Resistance Junction to Lead R <sub>BJL</sub>		15						°C/W	
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55+150			°C				

Note: 1. Mounted on glass epoxy PC board with 1.3mm<sup>2</sup> solder pad.

2. Measured at 1.0 MHZ and applied reverse voltage of 4.0 VDC

## **Ratings and Characteristics Curves**



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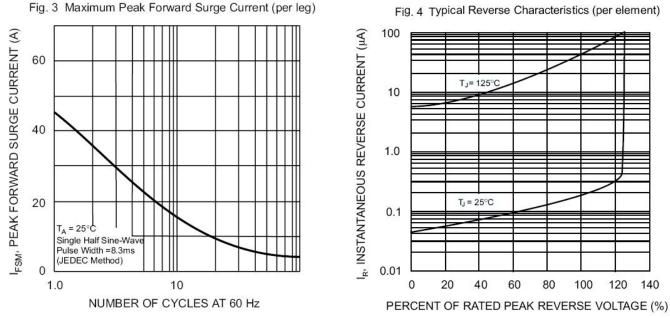
Fig. 2 Typical Forward Characteristics (per leg)



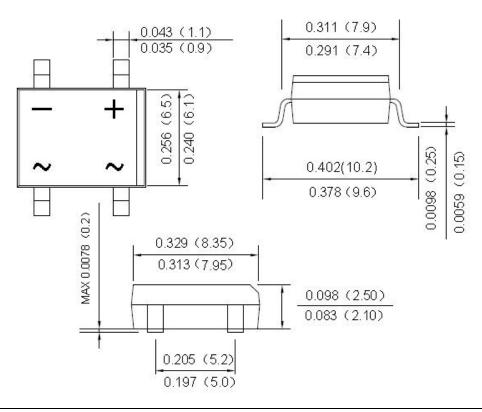
## DB101S THRU DB107S

#### Technical Data Data Sheet N1459, Rev. B





# Mechanical Dimensions DB-S(Inches/Millimeters)



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# DB101S THRU DB107S

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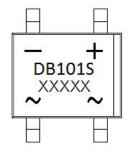


## **Ordering Information**

Device	Package	Plating	Shipping
DB101S THRU DB107S	DB-S (Pb-Free)	Pure Sn	1500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**



Where XXXXX is YYWWL

- DB101S = Type Number
  - = Year

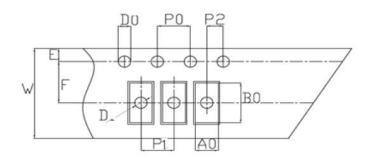
YY

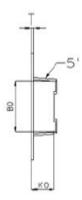
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ww

- = Week
- = Lot Number
- Cautions: Molding resin Epoxy resin UL:94V-0

### **Carrier Tape Specification DB-S**





SYMBOL	Millimeters					
STMBOL	Min.	Max.				
A0	8.65	8.95				
B0	10.31	10.51				
D0	1.50	1.60				
D1	1.40	1.60				
P0	3.90	4.10				
P1	11.90	12.10				
P2	1.90	2.10				
E	1.65	1.85				
K0	3.21	3.41				
F	7.40	7.60				
W	15.70	16.30				
Т	0.30	0.40				
10P0	39.80	40.20				



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# DB101S THRU DB107S



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